Product data sheet

1. General description

Three phase Rectifier Bridge in a WMM01 package.

2. Features and benefits

- · Three phase rectifiers
- · Heat transfer through aluminum oxide DBC, ceramic isolated metal baseplate
- High voltage capability
- · High inrush current capability
- Planar process
- High operating temperature capability (T_{i (max)} = 150°C)

3. Applications

- Three phase rectifiers for power supplies
- Rectifiers for DC motor field supplies
- Battery charger rectifiers
- · Input rectifiers for variable frequency drives

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Val	lues		Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			16	600		V
$\mathbf{I}_{\mathrm{D}(\mathrm{AV})}$	average output current	δ = 0.5 ; square-wave pulse	75			А	
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	750			А	
forward current		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	822			А	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V_{F}	forward voltage	I _F = 75 A; T _j = 25 °C		-	1.25	-	V

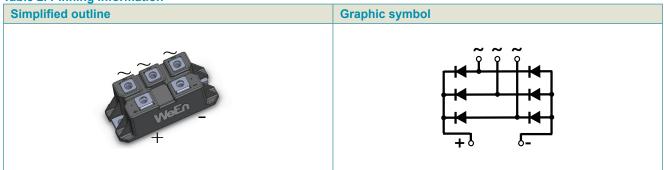
WeEn Semiconductors

WDMF75M16

Three Phase Rectifier Bridge

5. Pinning information

Table 2. Pinning information



6. Ordering information

Table 3. Ordering information

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	3	Package issue date
WDMF75M16	WMM01	WDMF75M16T	Tray	8	WMM01	17-Dec-2018

7. Marking

Table 4. Marking codes

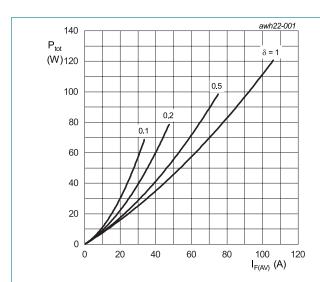
Type number	Marking codes
WDMF75M16	WDMF75M16

8. Limiting values

Table 5. Limiting values

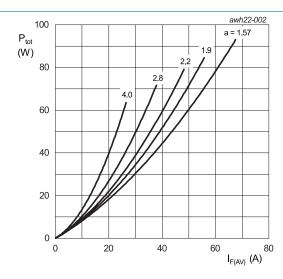
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1600	V
V_{RWM}	crest working reverse voltage		1600	V
V_R	reverse voltage	DC	1600	V
I _{D(AV)}	average output current	δ = 0.5 ; square-wave pulse	75	А
I _{FRM}	average output current	δ = 0.5 ; square-wave pulse; t_p = 25 us	150	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	750	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	822	А
I ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	2813	A²s
		t _p = 8.3 ms; sine-wave pulse	2814	A²s
V _{isol}	isolation breakdown voltage	AC 50Hz; 1 s / 1 min	3600/3000	V
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		150	°C
Mounting Torque	to terminal (M5)		3 +/- 15%	Nm
	to heatsink (M5)		5 +/- 15%	Nm
Weight	approximate weight	Module	155	g



$$\begin{split} I_{\text{F(AV)}} &= I_{\text{F(RMS)}} \times \sqrt{\delta} \\ V_{\text{o}} &= 0.719 \text{ V; } R_{\text{s}} = 0.0040 \text{ }\Omega \end{split}$$
 Fig. 1. Forward power dissipation as a function of average forward current; square waveform;

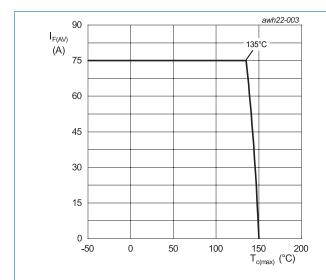
maximum values

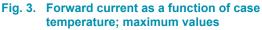


a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.719 V; R_s = 0.0040 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

Three Phase Rectifier Bridge





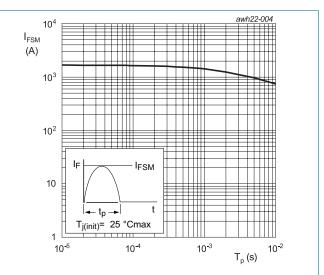


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-c)}}$	thermal resistance from junction to case	per module	-	-	0.15	K/W

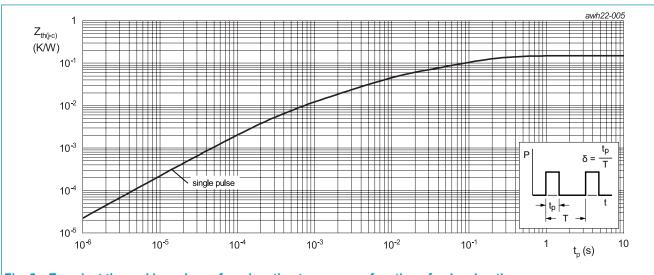


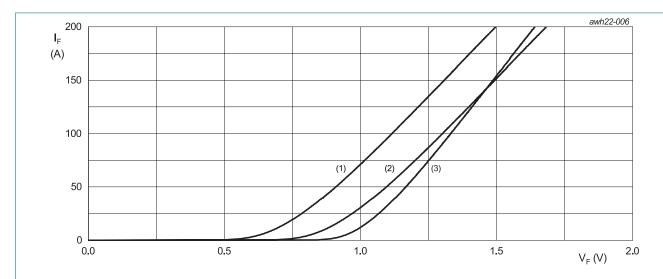
Fig. 5. Transient thermal impedance from junction to case as a function of pulse duration

Three Phase Rectifier Bridge

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 75 A; T _j = 25 °C	-	1.25	-	V
		I _F = 75 A; T _j = 125 °C	-	1.2	-	V
I _R	reverse current	V _R = 1600 V; T _j = 25 °C	-	-	50	μA
		V _R = 1600 V; T _j = 150 °C	-	-	5	mA



 V_o = 0.719 V; R_s = 0.0040 Ω

(1) T_i = 125 °C; typical values

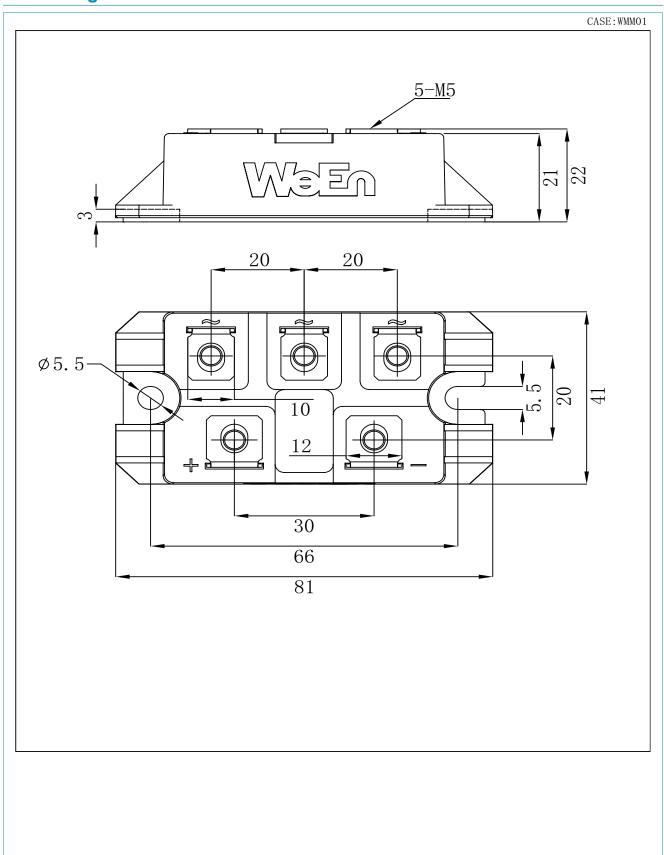
(2) T_i = 125 °C; maximum values

(3) $T_j = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage

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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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